

ROOM-TEMPERATURE, SOLID-STATE QUANTUM SENSORS

Michael Trupke,
University of Vienna

OVERVIEW

Consortium



SAL

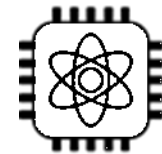


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Project



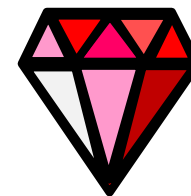
QSense4Life

Aim

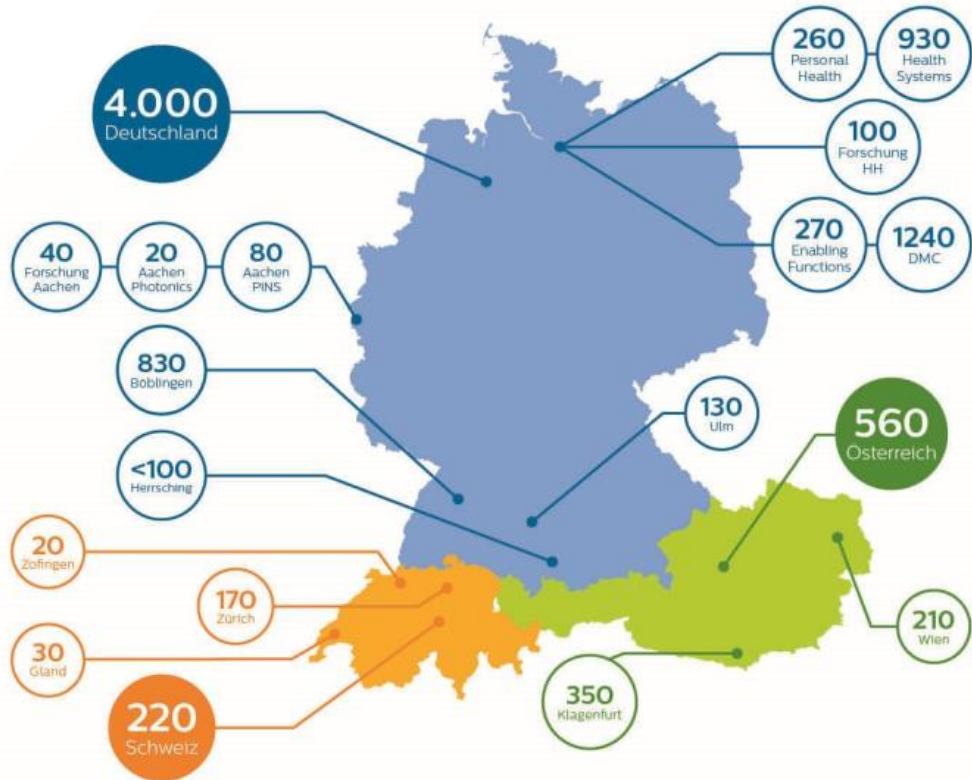
Desktop-scale system for
fluid NMR/ESR analysis

Based on

Quantum sensor qubits in diamond



PHILIPS HEALTHCARE - APPLICATIONS

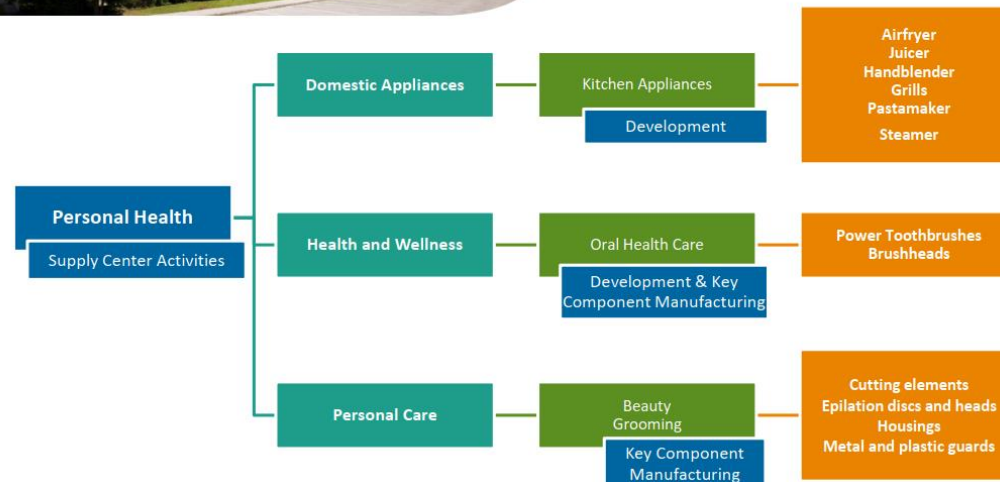


Philips Klagenfurt within Philips Personal Health



Worldwide activities in healthcare

Advanced Molecular Imaging	Emergency Care and Resuscitation Solutions	Medical parts & supplies
Breathing and Respiratory care	Enterprise telehealth portfolio	Mother & Child Care
Clinical Informatics	Fluoroscopy	MRI Systems & Solutions
Computed Tomography Machines & Solutions	Hospital Respiratory Care	Pathology
Customer Service Solutions	Image Guided Therapy Devices	Patient Monitoring
Diagnostic ECG	Interventional X-ray Systems and Solutions	Radiation Oncology
EEG Neuroimaging		Radiography
		Refurbished Systems
		Sleep
		Ultrasound



INFINEON TECHNOLOGIES AUSTRIA – PRODUCTION

Product palette



Automotive

- › 32-Bit-Mikrocontroller für Antriebsstrang, Sicherheit und Fahrerassistenzsysteme
- › 3D ToF-Sensoren
- › Diskrete Leistungshalbleiter
- › Druck- und Magnetfeldsensoren
- › IGBT-Module
- › Industrie-Mikrocontroller
- › Leistungs-ICs
- › Radar-Sensor-ICs (77 GHz)
- › Spannungsregler
- › Transceiver (CAN, LIN, Ethernet, FlexRay™)



Industrial Power Control

- › "Bare Die"-Geschäft
- › Diskrete IGBTs
- › IGBT-Module für niedrige, mittlere und hohe Leistungsklassen
- › IGBT-Modul-Lösungen inkl. IGBT-Stacks
- › Intelligente IGBT-Module mit integrierter Steuerung, Treiber und Schalter
- › Siliziumkarbid-MOSFETs und -Module
- › Treiber-ICs



Power Management & Multimarket

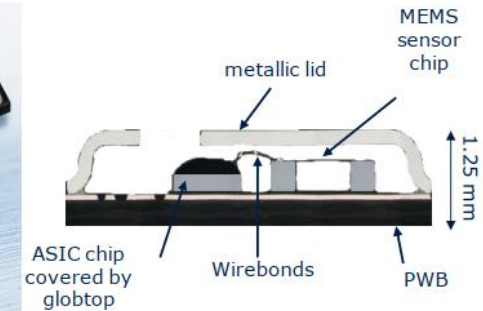
- › Ansteuer-ICs
- › Chips für Silizium-Mikrofone
- › Diskrete Niedervolt- und Hochvolt-Leistungshalbleiter
- › Chips für Drucksensoren
- › GPS-Signalverstärker
- › HF-Antennenschalter
- › HF-Leistungstransistoren
- › Kundenspezifische Chips (ASICs)
- › Niedervolt- und Hochvolt-Treiber-ICs
- › Radarsensor-ICs (24 GHz, 60 GHz)
- › Schutzdioden gegen elektrostatische Entladung
- › Siliziumkarbid-Dioden



Digital Security Solutions

- › Eingebettete Sicherheitscontroller
- › Kontaktbasierte Sicherheitscontroller
- › Kontaktlose Sicherheitscontroller
- › Sicherheitscontroller mit kontaktloser sowie kontaktbasierter Schnittstelle (Dual-Interface)

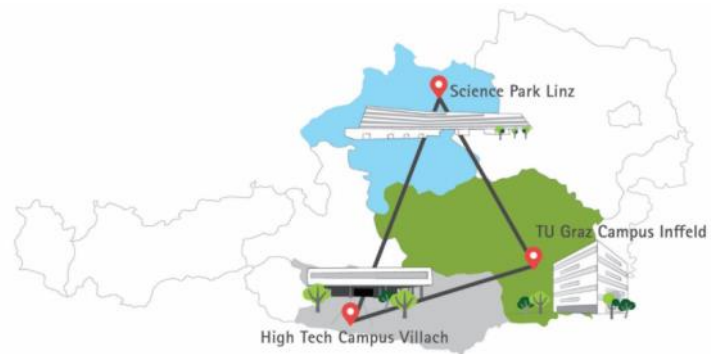
Product example: Silicon MEMS microphone



CTR → SILICON AUSTRIA LABS – COORDINATION AND SYSTEMS INTEGRATION



The Austrian Research Center for Electronic Based Systems



Financing & Company type

140 Mio. Euro public funding until 2023
140 Mio. Euro investment by industry partners
Public-Private-Partnership
GmbH (Ltd.) organized under private law



Graz – HQ
Systems Integration



Villach
Sensor Systems
Power Electronics



Linz
RF-Systems



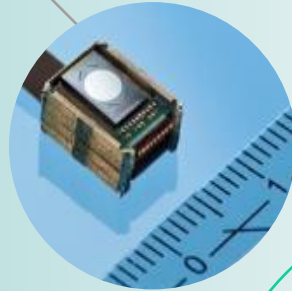
Shareholders

50.1 % Republic of Austria
10 % Styrian Business Promotion Agency SFG
10 % State of Carinthia
4.95 % Upper Austrian Research GmbH UAR
24.95 % Industrial Association FEEI

R & D AT SILICON AUSTRIA LABS (EX CTR)

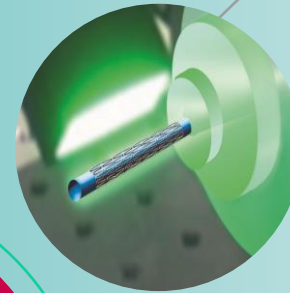
MICROSYSTEM- TECHNOLOGY

MEMS / MOEMS
Simulation/Design/Integration
MEMS Prozess-Technologies
Test & Characterisation



PHOTONIC SENSOR SYSTEMS

Raman
UV-VIS-NIR-MIR
Imaging
Laser Systems
THz



Bringing
Technologies
into
Application

PACKAGING & HETEROINTEGRATION

Functional packaging
Advanced packaging
Micro-Mechatronic Modules
Rapid Prototyping



SMART SYSTEMS

Systems for quality and
process control
SAW-based sensors
Photovoltaics
Sensores for e-mobility



Modelling & Design

Simulation

Experimental R&D

Prototyping

Characterisation

Testing

NETWORK OF RESEARCH AND INDUSTRY

Founded 1997

Employees 60 (+14 PhD students)
excl. Master students

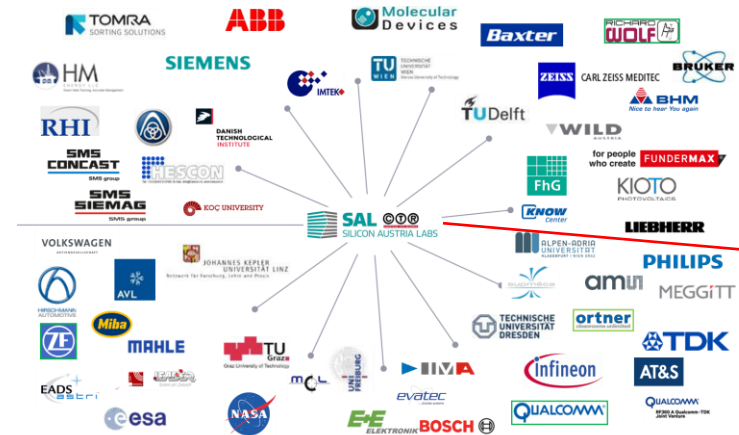
Turnover 2018 ~7 Mio.€

Shareholder Silicon Austria LABS GmbH
50,1% Republic of Austria
10% State of Carinthia
10% Styrian Business Promotion Agency SFG
4,95% Upper Austria Research GmbH UAR
24,95% Industrial Association FEEI

Network



Forschung Austria, EPoSS,
ECSEL Austria, IVAM, AG Sensorik,
AG Innovation IV, me2c Cluster
TU Wien, JKU Linz, AAU Klagenfurt,
TU Graz, TU Dresden, Uni Freiburg,
TU Clausthal, EPFL, TU Delft, CNRS,
KOC University

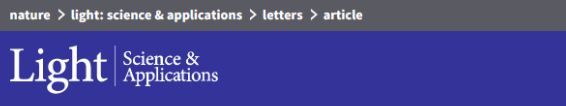


COMET K1 COMPETENCE CENTRE



UNIVIE – QUANTUM MICRO-DEVICES

Optical Microcavities

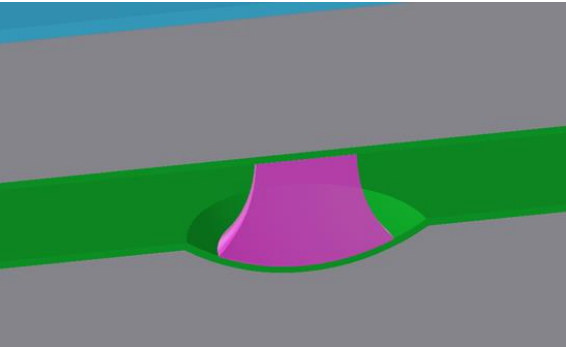


Letter | OPEN | Published: 10 April 2019

Silicon microcavity arrays with open access and a finesse of half a million

Georg Wächter, Stefan Kuhn, Stefan Minniberger, Cameron Salter, Peter Asenbaum, James Millen, Michael Schneider, Johannes Schalko, Ulrich Schmid, André Felgner, Dorothee Hüser, Markus Arndt & Michael Trupke

Light: Science & Applications 8, Article number: 37 (2019) | Download Citation



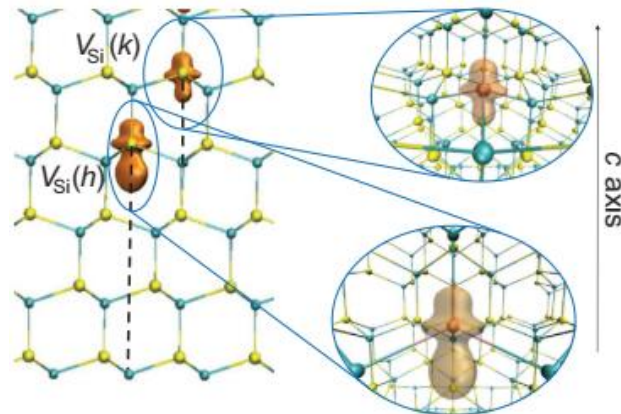
Qubits in Silicon Carbide

PHYSICAL REVIEW APPLIED (2019)

Optical Properties of Vanadium in 4H Silicon Carbide for Quantum Technology

L. Spindlberger,¹ A. Csóré,² G. Thiering,² S. Putz,^{3,*} R. Karhu,⁴ J. Ul Hassan,⁴ N.T. Son,⁴ T. Fromherz,¹ A. Gali,^{2,5} and M. Trupke^{3,†}

(accepted)

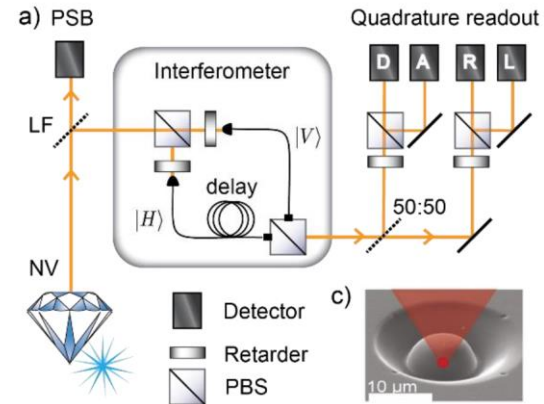


Spin-Photon Entanglement

Scalable spin-photon entanglement by time-to-polarization conversion

Rui Vasconcelos^{1,*}, Sarah Reisenbauer^{1,2,*}, Cameron Salter^{1,*}, Georg Wächter^{1,2}, Daniel Wirtitsch^{1,2}, Jörg Schmiedmayer², Philip Walther¹, and Michael Trupke^{1,2,*}

arXiv:1812.10338

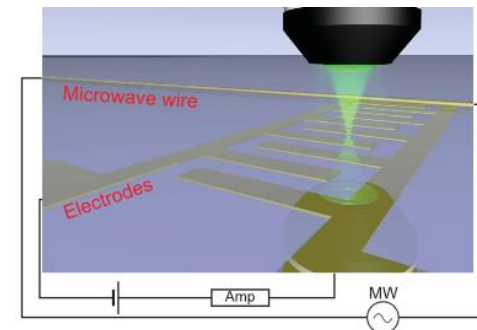


Electrical Qubit readout

Photoelectrical imaging and coherent spin-state readout of single nitrogen-vacancy centers in diamond

Petr Štyushev^{1,2,3,4}, Milos Nesladek^{5,6,7,8}, Emilie Bourgeois^{9,4}, Michal Gulka^{9,4,5}, Jaroslav Hrabý^{9,4}, Takashi Yamamoto^{9,4}, Michael Trupke⁴, Tokuyuki Teraji⁴, Junichi Isoya^{9,8}, Fedor Jelezko⁴

Science 15 Feb 2019; Vol. 363, Issue 6428, pp. 728-731 DOI: 10.1126/science.aav2789



PROJECT FLOW

Quantum Science and Technology

Coordination and Systems integration

Production and application



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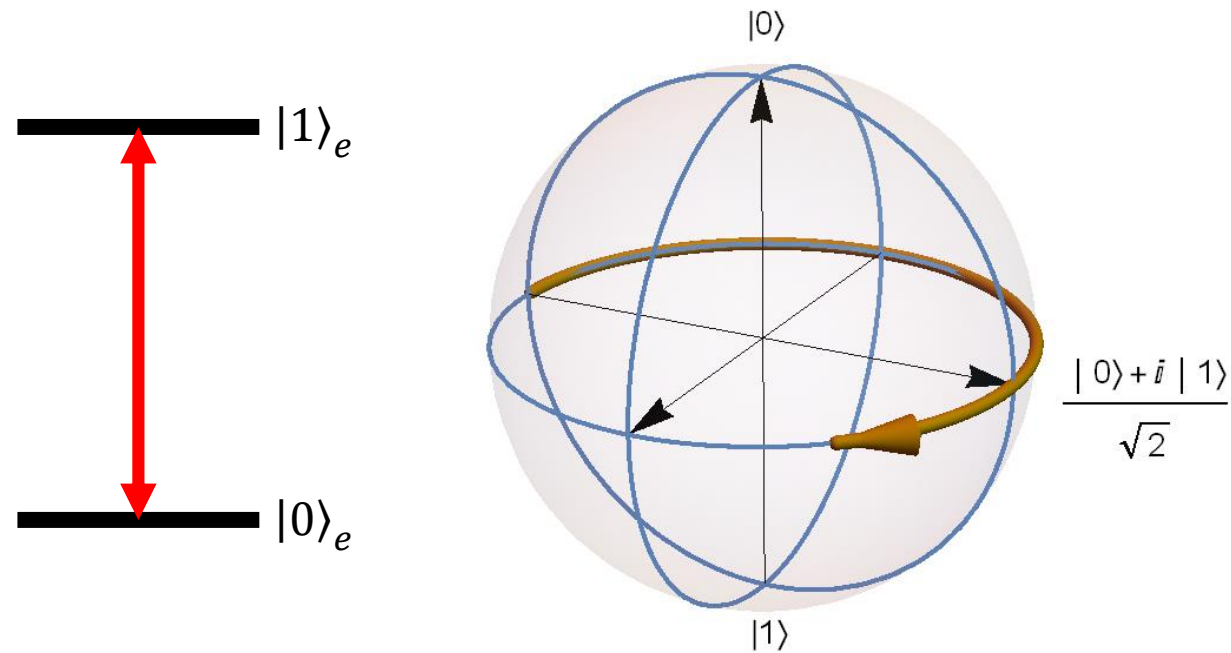
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WHAT IS A QUANTUM SENSOR?

A sensor which makes use of

- I. A quantum object
(can be nanoscale)
- II. Quantum interference
(high sensitivity)
- III. Quantum entanglement
($\propto N$ vs. $\propto \sqrt{N}$)



$$\psi = |0\rangle_e + e^{i\phi} |1\rangle_e$$

NITROGEN VACANCY

Defect in diamond lattice:
substitutional nitrogen with adjacent
vacancy

Spin-free environment

→ Long spin coherence time $> 2\text{ms}$

Optical initialisation and readout

Sensitive to magnetic and electric
fields, temperature, strain...

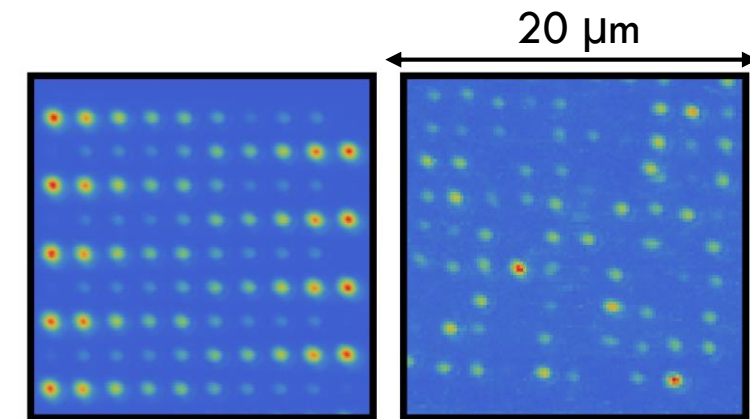
Nanoscale

non-toxic

Can be implanted



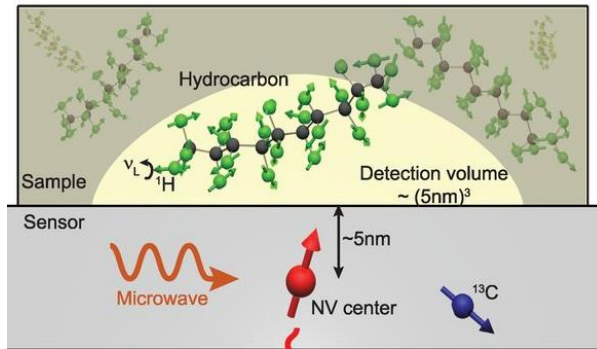
Meijer et al., *Appl. Phys. A*
83 2, 321-327 (2006)



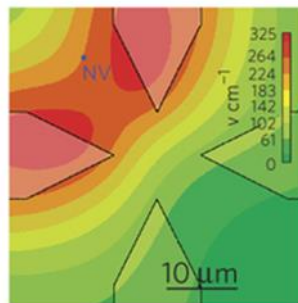
TUWIEN-UNIVIE

Review: Doherty, M. W., Manson, N. B., Delaney, P., Jelezko, F., Wrachtrup, J., & Hollenberg, L. C. „The nitrogen-vacancy colour centre in diamond“. *Physics Reports* **528**(1), 1-45 (2013).

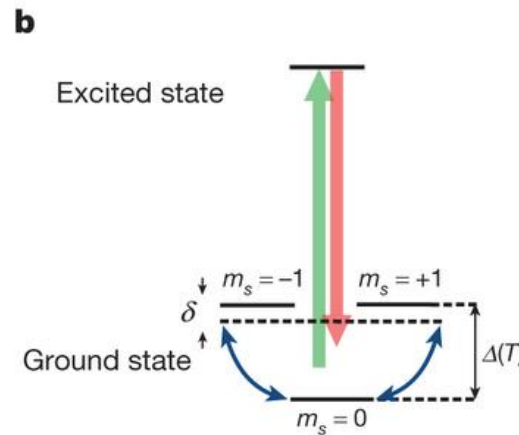
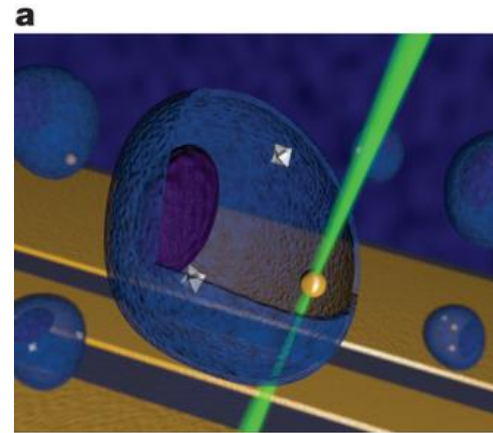
NV SENSING APPLICATIONS



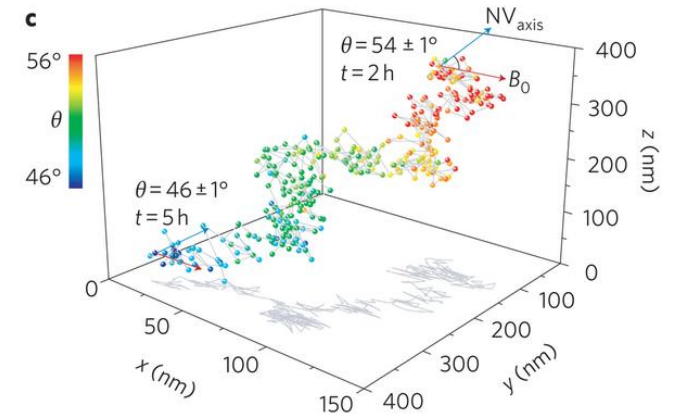
Nano-NMR (Wrachtrup, Jelezko, Walsworth groups)



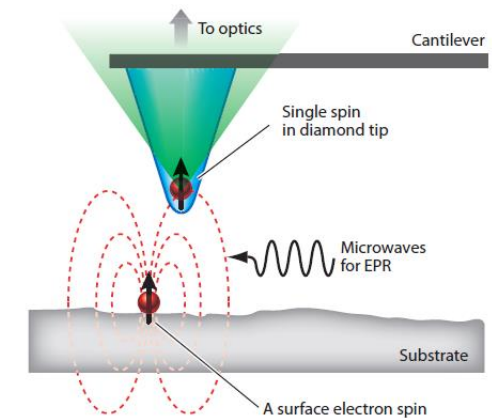
E-field sensing (Wrachtrup, Doherty groups)



In vivo Thermometry (Lukin, Wrachtrup groups)



In-vivo magnetometry (Wrachtrup, Prawer, Hollenberg groups)



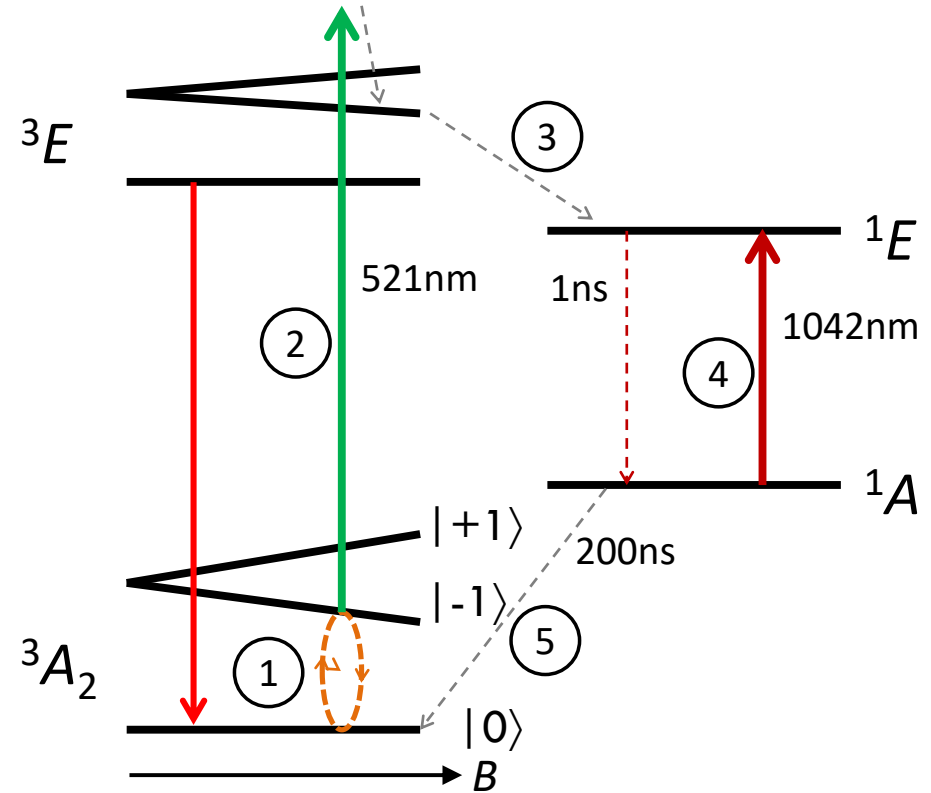
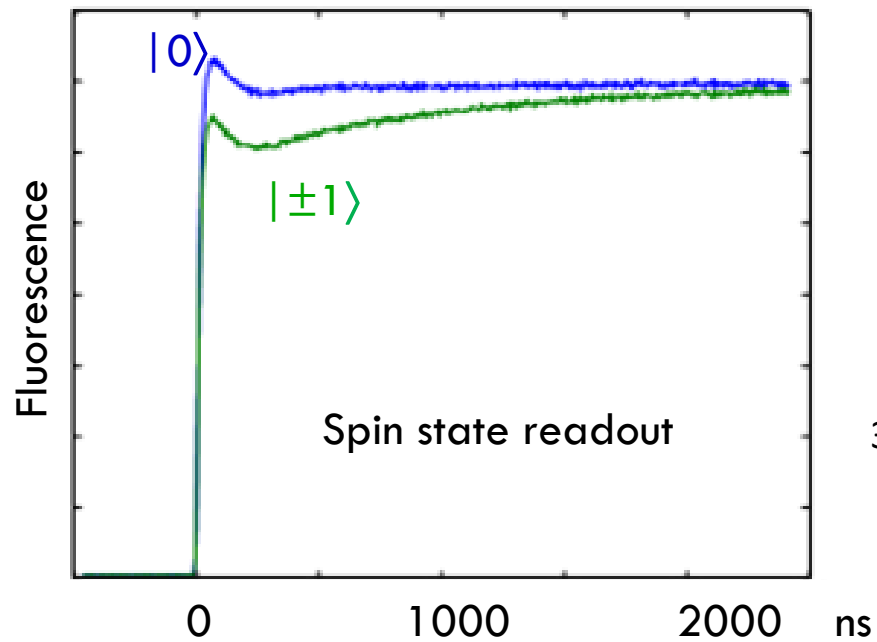
Scanning nano-sensor (Degen, Maletinsky, Lukin groups)

NV SPIN CONTROL AND READOUT – ROOM TEMP.

(Room temperature)

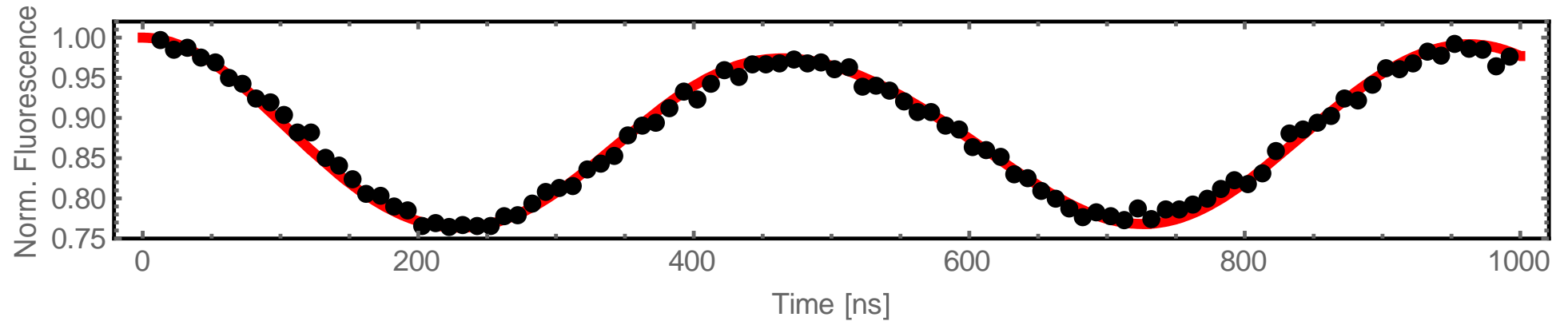
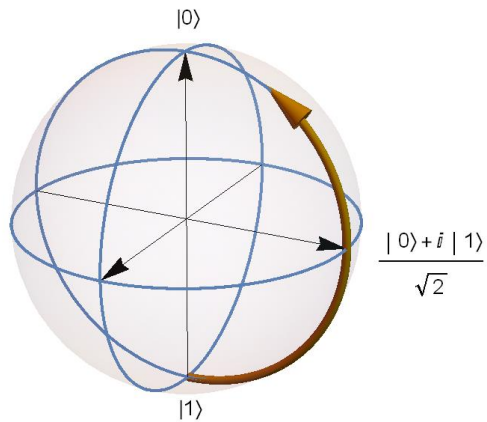
Laser-induced initialisation

Spin-dependent fluorescence



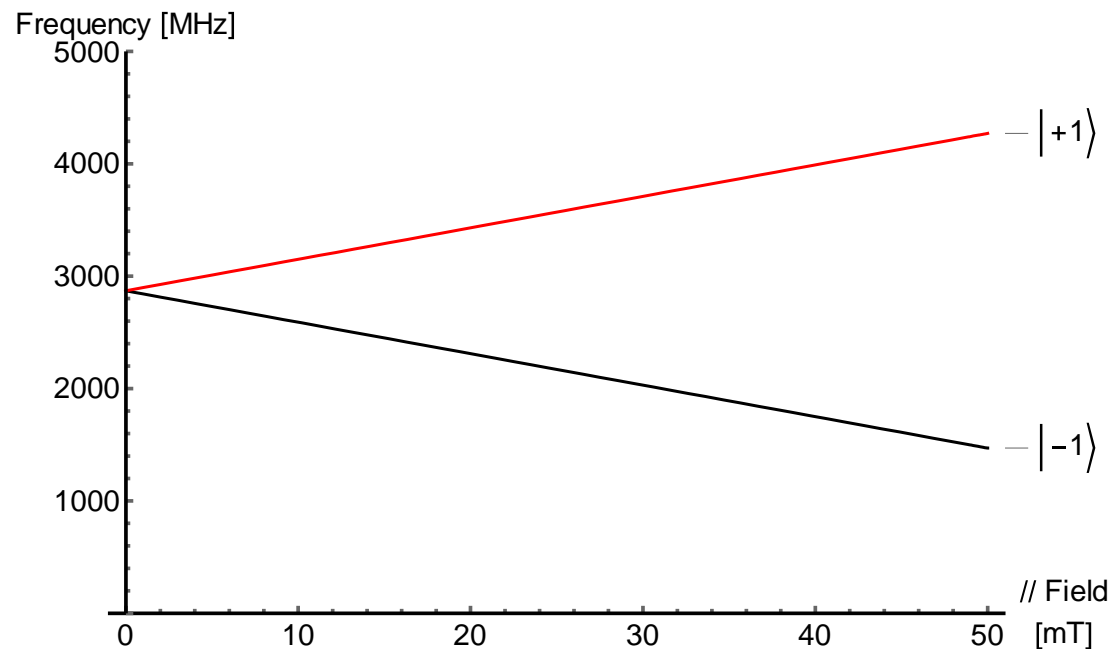
SPIN ROTATION OF THE ELECTRONIC QUBIT

The electron resides in a magnetically quiescent environment for long coherence lifetime ($>2\text{ms}$), enabling high-fidelity quantum state transfer and high-resolution spectroscopy



SENSING WITH NV CENTRES

$$H = \begin{pmatrix} 0 & g\mu_B\beta_{\perp} & g\mu_B\beta_{\perp}^* \\ g\mu_B\beta_{\perp}^* & D_g + d_{\parallel}E_z + g\mu_B B_z & d_{\perp}(E_x + iE_y) \\ g\mu_B\beta_{\perp} & d_{\perp}(E_x - iE_y) & D_g + d_{\parallel}E_z - g\mu_B B_z \end{pmatrix}$$

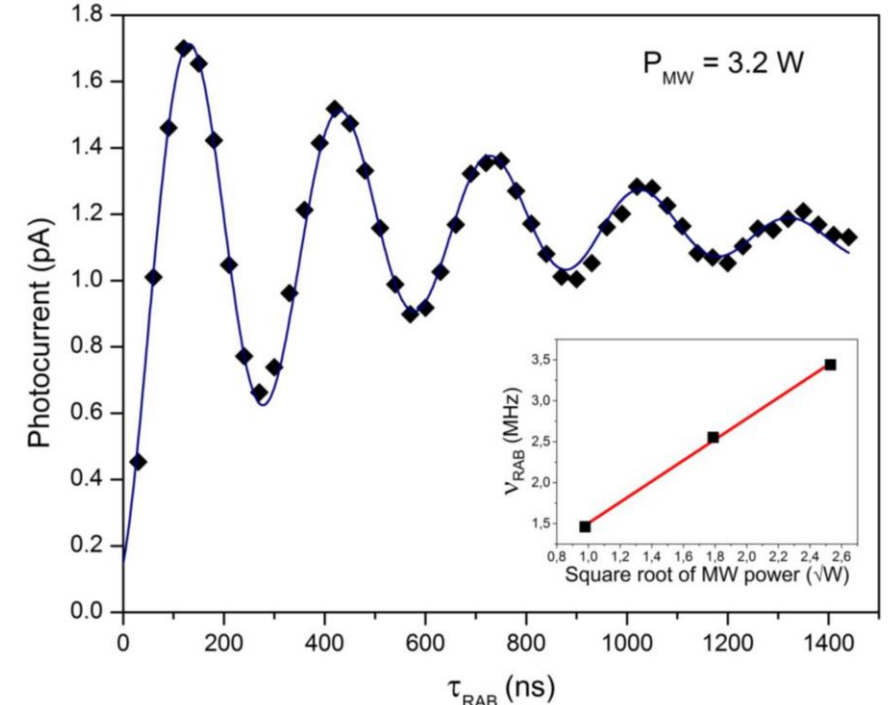
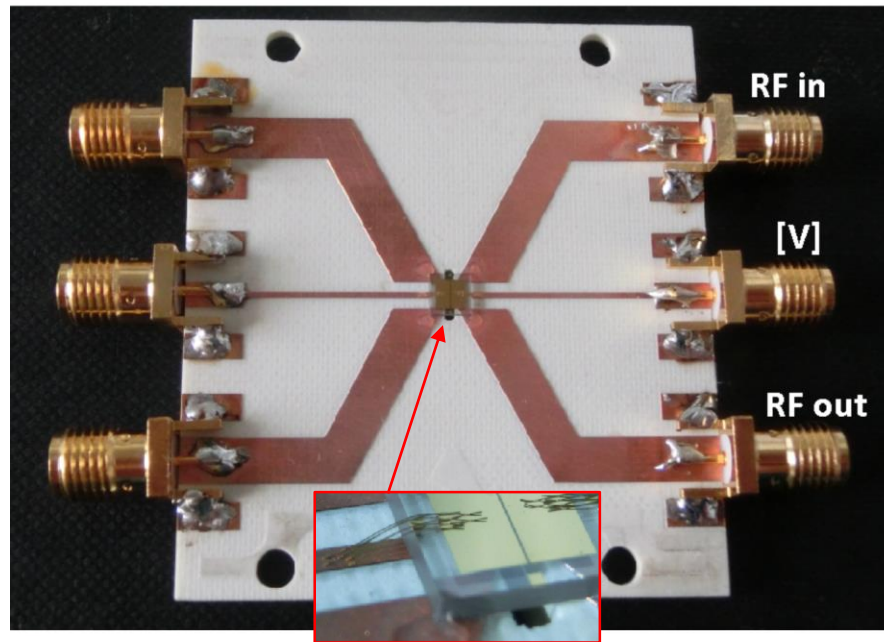
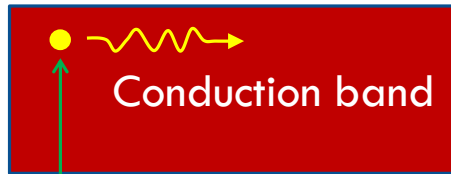


The spin-dependent fluorescence and the Zeeman shift due to magnetic field parallel to the NV axis enable:

- Sensitive measurements of **DC fields** (\sim nanotesla sensitivity for a single NV)
- **Vector magnetometry** using multiple NV centres (along four crystalline axes)
- Detection of **oscillating fields** originating from e.g. external nuclear spins

ELECTRICAL SPIN DETECTION

Convert spin to charge: spin-selective ionization. Does not require optical signal collection or expensive photon counters. Enhanced signal by more than $\times 1000$.



Valence band

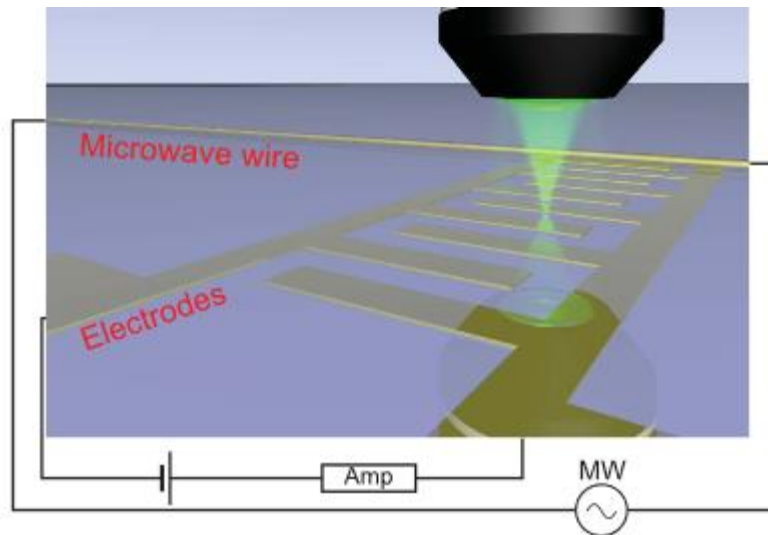
Gulka M, et al.. Pulsed Photoelectric Coherent Manipulation and Detection of NV Center Spins in Diamond.

Physical Review Applied. 2017 Apr 28;7(4):044032.

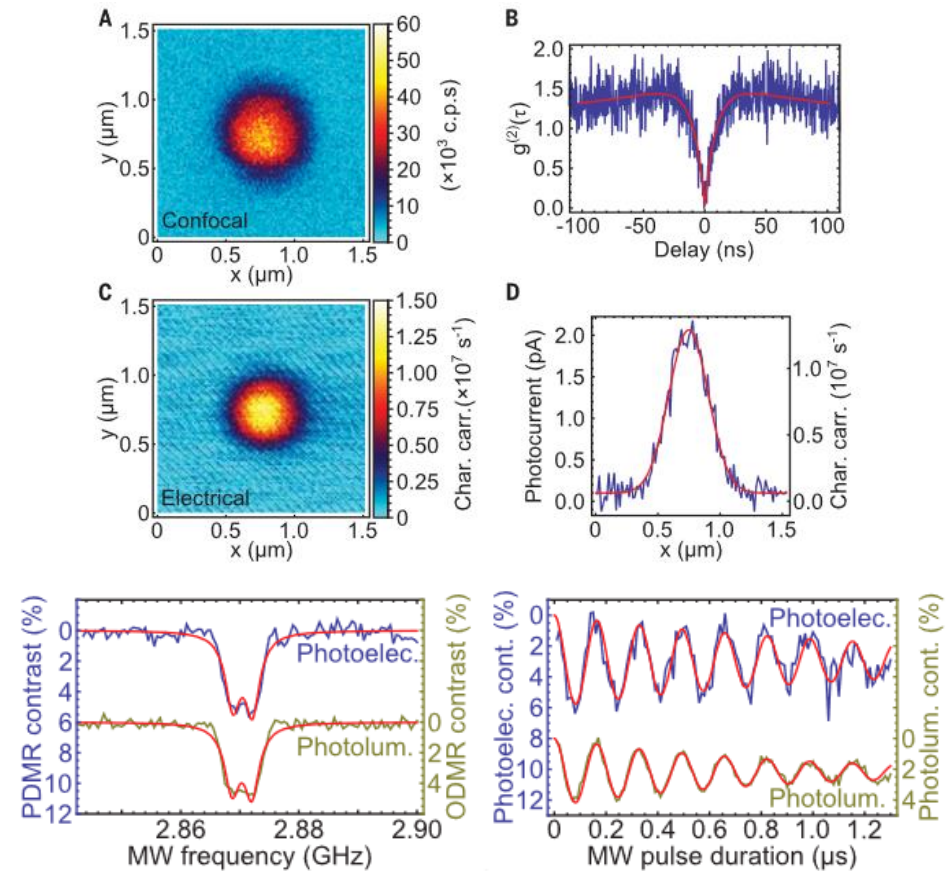
Bourgeois, E. et al., 2017. Enhanced photoelectric detection of NV magnetic resonances in diamond under dual-beam excitation.

Physical Review B, 95(4), p.041402.

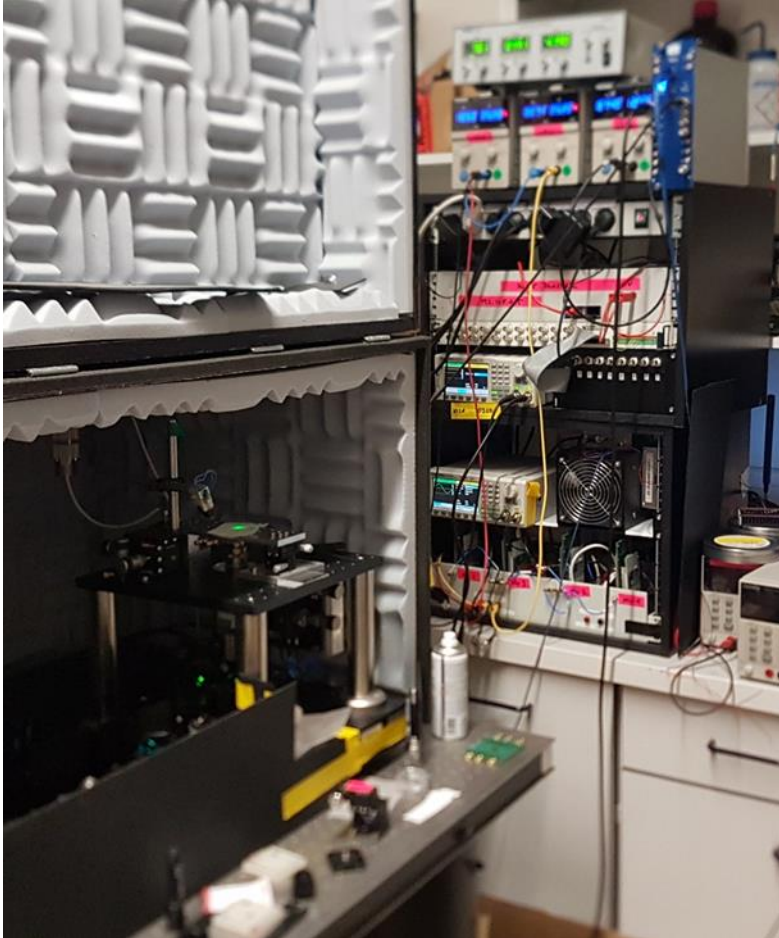
SINGLE QUBIT ELECTRICAL READOUT



P. Siyushev et al., *Science* **363**, 728-731 (2019)



AIM: COMPACT SENSOR FOR LIQUID ANALYTES

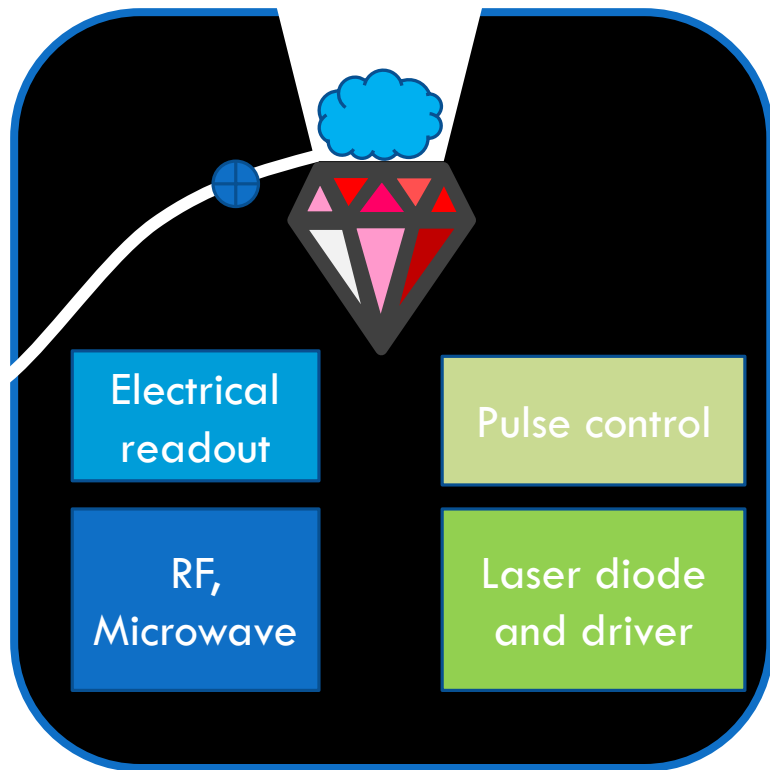


Desktop package enabling use of nano-ESR/NMR for:
health services, nutrition analysis,
citizen science, and more.



Requires robust design, detailed understanding of
molecular spin interactions, and extremely sensitive
readout electronics.

PROJECT: DEVICE OVERVIEW

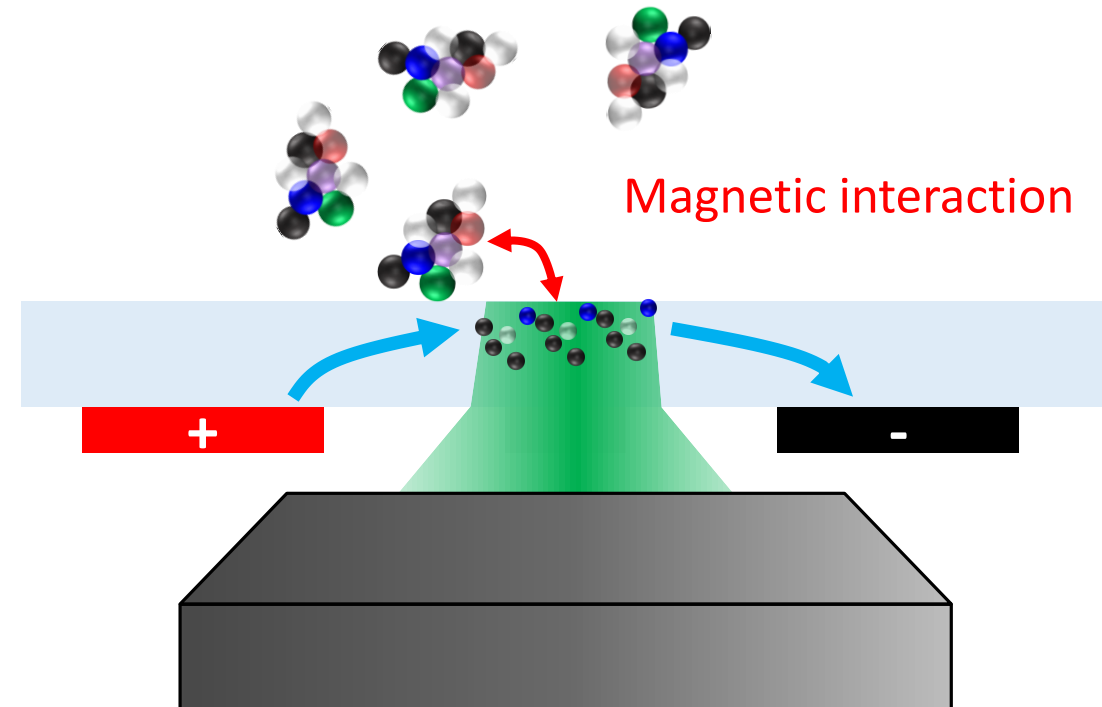


Molecules

Diamond with NVs

RF + Electrodes

Excitation optics



EXAMPLE OF INTEGRATION: SPIN-DEPENDENT PHOTOCURRENT AMPLIFIER

Presently used:

General-purpose
lock-in amplifier



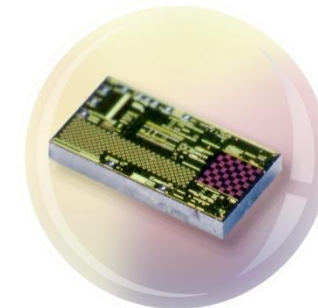
Next step:

Tailor-made multi-stage
using commercial IC



Final device:

Specialized IC



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TEAM AND SPONSORS



M.T.

G. Wachter

S. Reisenbauer

S. Putz

S. Minniberger



C. Hirschl

G. Auböck

K. Harms

J. Pribosek

T. Moldaschl

R. Leitner

F. Starmans

R. Waldner

F. Michl

H. Pairitsch

A. Moser

